

EAST Search History

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S51	32	semiconductor\$2 and (repair\$3 or coat\$3) and (((("si" or silicon) near2 oxide) same ((("y" or yttrium) near2 \$2oxide)) same ((rough\$4 with surface) or (crack\$4 or fissur\$3 or trench\$2 or via\$2)))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/05/14 14:58
S52	0	((semiconductor\$2 or (semi near2 conductor \$2)) with (repair\$3 or refurbish\$3 or restor \$3) same (rough\$4 or crack\$4 or fissur\$3 or trench\$2 or via\$2)) and (repair\$3 or coat\$3 or deposit\$3 or apply\$3 or supply\$3) same (((("si" or silicon) near2 oxide) same ((("y" or yttrium) near2 \$2oxide))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/05/14 15:09
S53	0	((semiconductor\$2 or (semi near2 conductor \$2)) same (repair\$3 or refurbish\$3 or restor \$3) same (rough\$4 or crack\$4 or fissur\$3 or trench\$2 or via\$2)) and (repair\$3 or coat\$3 or deposit\$3 or apply\$3 or supply\$3) same (((("si" or silicon) near2 oxide) same ((("y" or yttrium) near2 \$2oxide))	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/05/14 15:10
S54	111659	(semiconductor\$2 or (semi near2 conductor \$2)) same (repair\$3 or refurbish\$3 or restor\$3 or fix\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/05/14 15:28

S55	306331	((silic\$3 near2 oxide\$1) or "Sio.sub.2" or sio or silica) same (yttria or ("y.sub.2o.sub.3") or (yttri\$3 near2 oxide) or zirconia or (zirconi\$3 near2 oxide\$2) or "zro.sub.2" or alumina or (alumin\$3 near2 oxide) or "al.sub.2o.sub.3")	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/05/14 15:33
S56	4043	S54 and S55	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/05/14 15:33
S57	316	S54 same S55	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/05/14 15:33
S60	1520625	(rough\$4 or crack\$4 or fissur\$3 or trench\$2 or via\$2) same (repair\$3 or coat\$3 or deposit\$3 or apply\$3 or supply\$3 or fix\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/05/14 15:34
S61	164	S57 and S60	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/05/14 15:35
S62	67915	(semiconductor\$2 or (semi near2 conductor \$2)) with (repair\$3 or refurbish\$3 or restor\$3 or fix\$3)	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/05/14 15:38
S63	2372	S55 and S62	US-PGPUB; USPAT; USOCR; FPRS; EPO; JPO; DERWENT; IBM_TDB	ADJ	ON	2009/05/14 15:39
S64	75149	((silic\$3 near2 oxide\$1) or "Sio.sub.2" or sio or silica) same (yttria or ("y.sub.2o.sub.3") or (yttri\$3 near2 oxide) or zirconia or (zirconi\$3 near2 oxide\$2) or "zro.sub.2" or alumina or (alumin\$3 near2 oxide) or "al.sub.2o.sub.3")	EPO; JPO; DERWENT	ADJ	ON	2009/05/14 15:39

S65	30952	(semiconductor\$2 or (semi near2 conductor \$2)) with (repair\$3 or refurbish\$3 or restor\$3 or fix\$3)	EPO; JPO; DERWENT	ADJ	ON	2009/05/14 15:40
S66	82	S64 and S65	EPO; JPO; DERWENT	ADJ	ON	2009/05/14 15:40
S67	2513	(semiconductor\$2 or (semi near2 conductor \$2)) with (repair\$3 or refurbish\$3 or restor\$3)	EPO; JPO; DERWENT	ADJ	ON	2009/05/14 15:41
S68	11	S64 and S67	EPO; JPO; DERWENT	ADJ	ON	2009/05/14 15:41
S69	1	("6087191").PN.	US-PGPUB; USPAT; USOCR	OR	OFF	2009/05/14 16:09
S70	8	("4116714" "4129457" "4135952" "5217566" "5643649" "5934978").PN. OR ("6087191").URPN.	US-PGPUB; USPAT; USOCR	ADJ	ON	2009/05/14 16:09

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